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[OPA2156](http://www.ti.com/product/opa2156?qgpn=opa2156) SBOS900B –SEPTEMBER 2018–REVISED JUNE 2019

OPA2156 36-V, Ultra-Low Noise, Wide-Bandwidth, CMOS, Precision, Rail-to-Rail, Operational Amplifier

Technical [Documents](http://www.ti.com/product/OPA2156?dcmp=dsproject&hqs=td&#doctype2)

1 Features

- Ultra-low noise: 3 nV/ \sqrt{Hz} at 10 kHz
- Low offset voltage: ±25 µV
- Low offset voltage drift: $\pm 0.5 \mu V$ /°C
- Low bias current: $±5$ pA
- Common-Mode Rejection: 120dB
- Low Noise: 3 nV/√Hz at 10 kHz
- Wide bandwidth: 25-MHz GBW
- Open-loop voltage gain: 154 dB
- High output current: 100 mA
- Rail-to-rail input and output
- High slew rate: 40 V/µs
- Fast settling time: 600 ns (10-V step, 0.01%)
- Wide supply: ±2.25 V to ±18 V, 4.5 V to 36 V
- • Industry standard packages:
	- Dual in SOIC-8 and VSSOP-8

2 Applications

- Data acquisition (DAQ)
- Photodiode Transimpedance Amplifiers
- Vibration monitor module
- Analog input module
- High-Resolution ADC Driver Amplifiers
- Medical Equipment

1000 Voltage Noise Density (nV/vHz) Voltage Noise Density (nV/óHz) 100 10 1 100m 1 10 100 1k 10k 100k 1M 10M Frequency (Hz) D008

3 Description

Tools & **[Software](http://www.ti.com/product/OPA2156?dcmp=dsproject&hqs=sw&#desKit)**

The OPA2156 is the first in a planned new generation of 36-V, rail-to-rail operational amplifiers (op amps).

Support & **[Community](http://www.ti.com/product/OPA2156?dcmp=dsproject&hqs=support&#community)**

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This devices offers very low offset voltage $(\pm 25 \mu V)$, drift $(\pm 0.5 \mu V)^{\circ}C$, and low bias current $(\pm 5 \mu A)$ combined with very low broadband voltage noise (3 nV/\sqrt{Hz}).

Unique features, such as rail-to-rail input and output voltage ranges, wide bandwidth (25 MHz) high output current (100 mA), and high slew rate (40 V/us) make the OPA2156 a robust, high-performance operational amplifier for high-voltage precision industrial applications.

The OPA2156 op amp is available in 8-pin SOIC and VSSOP packages and is specified over the industrial temperature range of –40°C to +125°C.

Device Information[\(1\)](#page-0-0)

(1) For all available packages, see the package option addendum at the end of the data sheet.

Low Input Voltage Noise Spectral Density OPA2156 Transimpedance Configuration

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, **44** intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (December 2018) to Revision B Page

Changes from Original (September 2018) to Revision A Page

• First release of production-data data sheet.. [1](#page-0-3)

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5 Pin Configuration and Functions

Pin Functions

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) $⁽¹⁾$ </sup>

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. Theseare stress ratings only, which do not imply functional operation of the device at these or anyother conditions beyond those indicated under *[Recommended](#page-3-3) Operating [Conditions](#page-3-3)*. Exposure to absolute-maximum-rated conditions for extendedperiods may affect device reliability.

(2) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

(1) JEDEC document JEP155 states that 500-V HBM allows safemanufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safemanufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

(1) Please see Thermal [Considerations](#page-17-0) section for information on ambient vs device junction temperature

6.4 Thermal Information: OPA2156

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953.](http://www.ti.com/lit/an/spra953c/spra953c.pdf)

6.5 Electrical Characteristics

Electrical Characteristics (continued)

at $T_A = 25^{\circ}$ C, $V_S = \pm 2.25V$ to $\pm 18V$, $V_{CM} = V_{OUT} = V_S / 2$, and $R_L = 2$ k Ω connected to $V_S / 2$ (unless otherwise noted)

6.6 Typical Characteristics

Table 1. Table of Graphs

at $T_A = 25^{\circ}C$, $V_S = \pm 18$ V, $V_{CM} = V_S / 2$, $R_L = 10$ k Ω connected to $V_S / 2$, and $C_L = 30$ pF (unless otherwise noted)

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at T_A = 25°C, V_S = ±18 V, V_{CM} = V_S / 2, R_L = 10 kΩ connected to V_S / 2, and C_L = 30 pF (unless otherwise noted) 140 -12 -12.5 -13 Short Circuit Current (mA) Short Circuit Current (mA) 120 -13.5 85 °C Output Voltage (V) Output Voltage (V) -14 -14.5 125 °C 100 -15 -15.5 -16 80 -16.5 $-40 °C$ -17 $25 °C$ -17.5 60 -18 60 80
Output Current (mA) -40 -20 0 20 40 60 80 100 120 0 20 40 60 80 100 120 140 Temperature (°C) **Figure 25. Short-Circuit Current vs Temperature Figure 26. Negative Output Voltage vs Output Current** 80 Vin (V) Vout (V) 70 60 Phase Margin (°) Phase Margin (°) /oltage (5V/div) Voltage (5V/div) 50 40 30 20 10 $0\frac{L}{10}$ 10 100 1000 1000 Time (100 μ s/div) Cload (pF) **Figure 27. No Phase Reversal Figure 28. Phase Margin vs Capacitive Load** 70 100 $R_{ISO} = 0$ $R_{ISO} = 0$ 90 $R_{ISO} = 25$ $R_{ISO} = 25$ 60 $R_{ISO} = 50$ $R_{ISO} = 50$ 80 50 70 <u>ک</u> <u>୍ଚ</u> 60 40 Overshoot (Overshoot (50 30 40 30 20 20 10 10 $0\frac{L}{10}$ $\frac{0}{10}$ 10 100 1000 1000 10 100 1000 1000 Capactiance (pF) Capactiance (pF) 10-mV output step, gain $= -1$ 10-mV output step, gain $= +1$

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Figure 29. Small Signal Overshoot vs Capacitive Load

Figure 30. Small Signal Overshoot vs Capacitive Load

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at $T_A = 25^{\circ}$ C, V_S = ±18 V, V_{CM} = V_S / 2, R_L = 10 kΩ connected to V_S / 2, and C_L = 30 pF (unless otherwise noted)

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7 Detailed Description

7.1 Overview

The OPA2156 is laser trimmed to improve offset and uses a three-gain-stage architecture to achieve very low noise and distortion. The *[Functional](#page-14-2) Block Diagram* shows a simplified schematic of the OPA2156 (one channel shown). The device consists of a low noise input stage and feed-forward pathway coupled to a high-current output stage. This topology exhibits superior distortion performance under a wide range of loading conditions compared to other operational amplifiers.

7.2 Functional Block Diagram

7.3 Feature Description

7.3.1 Phase Reversal Protection

The OPA2156 has internal phase-reversal protection. Many op amps exhibit phase reversal when the input is driven beyond the linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The input of the OPA2156 prevents phase reversal with excessive common-mode voltage. Instead, the appropriate rail limits the output voltage. This performance is shown in [Figure](#page-14-4) 42.

Figure 42. Output Waveform Devoid of Phase Reversal During an Input Overdrive Condition

[OPA2156](http://www.ti.com/product/opa2156?qgpn=opa2156)

Texas **INSTRUMENTS**

Feature Description (continued)

7.3.2 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but can involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

A good understanding of this basic ESD circuitry and the relevance to an electrical overstress event is helpful. [Figure](#page-15-0) 43 illustrates the ESD circuits contained in the OPA2156 (indicated by the dashed line area). The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines, where the diodes meet at an absorption device internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.

Figure 43. Equivalent Internal ESD Circuitry Relative to a Typical Circuit Application

An ESD event produces a short-duration, high-voltage pulse that is transformed into a short-duration, highcurrent pulse when discharging through a semiconductor device. The ESD protection circuits are designed to provide a current path around the operational amplifier core to prevent damage. The energy absorbed by the protection circuitry is then dissipated as heat.

When an ESD voltage develops across two or more amplifier device pins, current flows through one or more steering diodes. Depending on the path that the current takes, the absorption device can activate. The absorption device has a trigger, or threshold voltage, that is above the normal operating voltage of the OPA2156 but below the device breakdown voltage level. When this threshold is exceeded, the absorption device quickly activates and clamps the voltage across the supply rails to a safe level.

Feature Description (continued)

When the operational amplifier connects into a circuit (see [Figure](#page-15-0) 43), the ESD protection components are intended to remain inactive and do not become involved in the application circuit operation. However, circumstances may arise where an applied voltage exceeds the operating voltage range of a given pin. If this condition occurs, there is a risk that some internal ESD protection circuits can turn on and conduct current. Any such current flow occurs through steering-diode paths and rarely involves the absorption device.

[Figure](#page-15-0) 43 shows a specific example where the input voltage (V_{N}) exceeds the positive supply voltage (V+) by 500 mV or more. Much of what happens in the circuit depends on the supply characteristics. If V+ can sink the current, one of the upper input steering diodes conducts and directs current to V+. Excessively high current levels can flow with increasingly higher V_{IN} . As a result, the data sheet specifications recommend that applications limit the input current to 10 mA.

If the supply is not capable of sinking the current, V_{IN} can begin sourcing current to the operational amplifier and then take over as the source of positive supply voltage. The danger in this case is that the voltage can rise to levels that exceed the operational amplifier absolute maximum ratings.

Another common question involves what happens to the amplifier if an input signal is applied to the input when the power supplies (V+ or V–) are at 0 V. Again, this question depends on the supply characteristic when at 0 V, or at a level below the input signal amplitude. If the supplies appear as high impedance, then the input source supplies the operational amplifier current through the current-steering diodes. This state is not a normal bias condition; most likely, the amplifier does not operate normally. If the supplies are low impedance, then the current through the steering diodes can become quite high. The current level depends on the ability of the input source to deliver current, and any resistance in the input path.

If there is any uncertainty about the ability of the supply to absorb this current, add external Zener diodes to the supply pins; see [Figure](#page-15-0) 43. Select the Zener voltage so that the diode does not turn on during normal operation. However, the Zener voltage must be low enough so that the Zener diode conducts if the supply pin begins to rise above the safe-operating, supply-voltage level.

Feature Description (continued)

7.3.3 Thermal Considerations

Through normal operation the OPA2156 will experience self-heating, a natural increase in the die junction temperature which occurs in every amplifier. This is a result of several factors including the quiescent power consumption, the package's thermal dissipation, PCB layout and the device operating conditions.

To fully ensure the amplifier will operate without entering thermal shutdown it is important to calculate the approximate junction (die) temperature which can be done using [Equation](#page-17-1) 1.

$$
T_{J} = P_D * \Theta J_A + T_A \tag{1}
$$

 $T_J = P_D * \Theta J_A + T_A$
ation 2 shows the approximation 2 shows the approximation of 25°C.
= $(36V * 4.4mA) * 12$
= $44°C$ [Equation](#page-17-2) 2 shows the approximate junction temperature for the OPA2156 while unloaded with an ambient temperature of 25°C.

$$
T_{J} = (36V * 4.4mA) * 120°C / W + 25°C
$$

$$
T_{\rm J}=44^{\circ}C
$$

For high voltage, high precision amplifiers such as the OPA2156 the junction temperature can easily be 10s of degrees higher than the ambient temperature in a quiescent (unloaded) condition. If the device then begins to drive a heavy load the junction temperature may rise and trip the thermal shutdown circuit. The [Figure](#page-17-3) 44 shows the maximum output voltage of the OPA2156 without entering thermal shutdown vs ambient temperature in both a loaded and unloaded condition.

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Feature Description (continued)

7.3.4 Thermal Shutdown

The internal power dissipation of any amplifier causes the internal (junction) temperature to rise. This phenomenon is called *self heating*. The OPA2156 has a thermal protection feature that prevents damage from self heating.

This thermal protection works by monitoring the temperature of the output stage and turning off the op amp output drive for temperatures above approximately 170°C. Thermal protection forces the output to a highimpedance state. The OPA2156 is also designed with approximately 15°C of thermal hysteresis. Thermal hysteresis prevents the output stage from cycling in and out of the high-impedance state. The OPA2156 returns to normal operation when the output stage temperature falls below approximately 155°C.

The absolute maximum junction temperature of the OPA2156 is 150°C. Exceeding the limits shown in the *Absolute [Maximum](#page-3-1) Ratings* table may cause damage to the device. Thermal protection triggers at 170°C because of unit-to-unit variance, but does not interfere with device operation up to the absolute maximum ratings. This thermal protection is not designed to prevent this device from exceeding absolute maximum ratings, but rather from excessive thermal overload.

7.3.5 Common-Mode Voltage Range

The OPA2156 is a 36-V, true rail-to-rail input operational amplifier with an input common-mode range that extends 100 mV beyond either supply rail. This wide range is achieved with paralleled complementary N-channel and P-channel differential input pairs. The N-channel pair is active for input voltages close to the positive rail, typically $(V+)$ – 2.25 V to 100 mV above the positive supply. The P-channel pair is active for inputs from 100 mV below the negative supply to approximately $(V+)$ – 1.25 V. There is a small transition region, typically $(V+)$ – 2.25V to $(V+)$ – 1.25 V in which both input pairs are active. This transition region varies modestly with process variation. Within this region PSRR, CMRR, offset voltage, offset drift, noise, and THD performance are degraded compared to operation outside this region.

To achieve the best performance for two-stage rail-to-rail input amplifiers, avoid the transition region when possible. The OPA2156 uses a precision trim for both the N-channel and P-channel regions. This technique enables significantly lower levels of offset than previous-generation devices, causing variance in the transition region of the input stages to appear exaggerated relative to offset over the full common-mode range.

7.3.6 Overload Recovery

Overload recovery is defined as the time required for the op amp output to recover from a saturated state to a linear state. The output devices of the op amp enter a saturation region when the output voltage exceeds the rated operating voltage, either due to the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return back to the linear state. After the charge carriers return back to the linear state, the device begins to slew at the specified slew rate. Thus, the propagation delay in case of an overload condition is the sum of the overload recovery time and the slew time.

7.4 Device Functional Modes

The OPA2156 has a single functional mode and is operational when the power-supply voltage is greater than 4.5 V (\pm 2.25 V). The maximum power supply voltage for the OPA2156 is 36 V (\pm 18 V).

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The OPA2156 offers excellent dc precision and ac performance. The device operates with up to 36-V supply rails offering true rail-to-rail input/output, low offset voltage and offset voltage drift, as well as 25-MHz bandwidth and low input bias. These features make the OPA2156 a robust, high-performance operational amplifier for high-voltage industrial applications.

8.1.1 Slew Rate Limit for Input Protection

In control systems for valves or motors, abrupt changes in voltages or currents can cause mechanical damages. By controlling the slew rate of the command voltages into the drive circuits, the load voltages ramps up and down at a safe rate. For symmetrical slew-rate applications (positive slew rate equals negative slew rate), one additional op amp provides slew-rate control for a given analog gain stage. The unique input protection and high output current and slew rate of the OPA2156 make the device an optimal amplifier to achieve slew rate control for both dual- and single-supply systems. [Figure](#page-19-2) 45 shows the OPA2156 in a slew-rate limit design.

Figure 45. Slew Rate Limiter Uses One Op Amp

For step-by-step design procedure, circuit schematics, bill of materials, PCB files, simulation results, and test results, refer to TI Precision Design [TIDU026,](http://www.ti.com/lit/pdf/TIDU026) *Slew Rate Limiter Uses One Op Amp*.

8.2 Typical Application

The combination of low input bias, high slew rate and a rail-to-rail input and output enable the OPA2156 to serve as an accurate differential photodiode transimpedance amplifier. This application example shows the design of such a system.

Figure 46. OPA2156 Configured as a Differential Photodiode Transimpedance Amplifier

8.2.1 Design Requirements

The design requirements for this design are:

- Photodiode current: 0 µA to 90 µA
- Output voltage: -5 V to 5 V
- Supply voltage: ±12 V
- Filter cutoff frequency: 1 MHz

8.2.2 Detailed Design Procedure

In this example the OPA2156 serves as a transimpedance amplifier for a differential photodiode. The differential configuration allows for a wider output range (0 to 10-V differential) compared to a single-ended configuration (0 V to 5 V). This output can be connected to a differential successive approximation register (SAR) analog-todigital converter (ADC). The basic equation for a differential transimpedance amplifier output voltage is shown in [Equation](#page-20-1) 3.

$$
V_{\text{OUT}} = I_{PD} \times 2 \times R_F
$$

(3)

[Equation](#page-20-1) 3 can be rearranged to calculate the value of the feedback resistors as shown in [Equation](#page-21-0) 4.

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(4)

Typical Application (continued)

$$
\frac{V_{OUT(MAX)} - V_{OUT(MIN)}}{2 \times I_{IN(MAX)}} \le R_F
$$

$$
\frac{5V - (-5V)}{2 \times 90 \mu A} \le 55.6 k\Omega
$$

Adding a capacitor to the feedback loop creates a filter which will remove undesired noise beyond its cutoff frequency. For this application a 1-MHz cutoff frequency was selected. The equation for an RC filter is provided in [Equation](#page-21-1) 5.

$$
fc = \frac{1}{2 \times \pi \times R_F \times C_F} \tag{5}
$$

Rearranging this equation to solve for the capacitor value is show in [Equation](#page-21-2) 6.

$$
C_F \le \frac{1}{2 \times \pi \times 54k\Omega \times 1MHz} \le 2.7 \, pF \tag{6}
$$

For more information on photodiode transimpedance amplifier system design and for a single-ended example, see *TIDU535: 1 MHz, [Single-Supply,](http://www.ti.com/lit/ug/tidu535/tidu535.pdf) Photodiode Amplifier Reference Design*.

8.2.3 Application Curves

9 Power Supply Recommendations

The OPA2156 is specified for operation from 4.5 V to 36 V (\pm 2.25 V to \pm 18 V); many specifications apply from –40°C to 125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical [Characteristics](#page-6-0)*.

CAUTION

Supply voltages larger than 40 V can permanently damage the device; see the *Absolute [Maximum](#page-3-1) Ratings*.

10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close as possible to the device. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
	- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
- Make sure to physically separate digital and analog grounds paying attention to the flow of the ground current. Separate grounding for analog and digital portions of circuitry is one of the simplest and mosteffective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup.
- In order to reduce parasitic coupling, run the input traces as far away as possible from the supply or output traces. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As shown in [Figure](#page-23-1) 50, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- Clean the PCB following board assembly for best performance.
- Any precision integrated circuit may experience performance shifts due to moisture ingress into the plastic package. After any aqueous PCB cleaning process, bake the PCB assembly to remove moisture introduced into the device packaging during the cleaning process. A low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

10.1.1 Power Dissipation

The OPA2156 op amp is capable of driving a variety of loads with a power-supply voltage up to ±18 V and full operating temperature range. Internal power dissipation increases when operating at high supply voltages and/or high output currents. Copper leadframe construction used in the OPA2156 improves heat dissipation compared to conventional materials. Circuit board layout can also help minimize junction temperature rise. Wide copper traces help dissipate the heat by acting as an additional heat sink. Temperature rise can be further minimized by soldering the devices to the circuit board rather than using a socket.

Layout Guidelines (continued)

The OPA2156 has an internal thermal protection feature which prevents it from being damaged due to self heating, or the internal heating generated during normal operation. The protection circuitry works by monitoring the temperature of the output stage and turns of the output drive if the junction temperature of the device rises to approximately 170°C. The device has a thermal hysteresis of approximately 15°C, which allows the device to safely cool down before returning to normal operation at approximately 155°C. TI recommends that the system design takes into account the thermal dissipation of the OPA2156 to ensure that the recommended operating junction temperature of 125°C is not exceeded to avoid decreasing the lifespan of the device or permanently damaging the amplifier.

10.2 Layout Example

Figure 50. Operational Amplifier Board Layout for Noninverting Configuration

11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

11.1.1.1 TINA-TI™ (Free Software Download)

TINA™ is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI is a free, fully-functional version of the TINA software, preloaded with a library of macro models in addition to a range of both passive and active models. TINA-TI provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free [download](http://www.ti.com/tool/tina-ti) from the Analog eLab Design Center, TINA-TI offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

NOTE

These files require that either the TINA software (from DesignSoft™) or TINA-TI software be installed. Download the free TINA-TI software from the [TINA-TI](http://www.ti.com/tool/tina-ti) folder at [http://www.ti.com/tool/tina-ti.](http://www.ti.com/tool/tina-ti)

11.1.1.2 TI Precision Designs

TI Precision Designs, available online at [http://www.ti.com/ww/en/analog/precision-designs/,](http://www.ti.com/ww/en/analog/precision-designs/) are analog solutions created by TI's precision analog applications experts and offer the theory of operation, component selection, simulation, complete PCB schematic and layout, bill of materials, and measured performance of many useful circuits.

11.2 Documentation Support

11.2.1 Related Documentation

- Texas Instruments, *EMI Rejection Ratio of [Operational](http://www.ti.com/lit/pdf/SBOA128) Amplifiers* application report
- Texas Instruments, *0-1A, [Single-Supply,](http://www.ti.com/lit/pdf/TIDU040) Low-Side, Current Sensing Solution* reference design
- Texas Instruments, *Op Amps for [Everyone](http://www.ti.com/lit/pdf/SLOD006)* design reference

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms](http://www.ti.com/corp/docs/legal/termsofuse.shtml) of [Use.](http://www.ti.com/corp/docs/legal/termsofuse.shtml)

TI E2E™ Online [Community](http://e2e.ti.com) *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design [Support](http://support.ti.com/) *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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11.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.7 Glossary

[SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TEXAS

TAPE AND REEL INFORMATION

STRUMENTS

*All dimensions are nominal

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

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PACKAGE MATERIALS INFORMATION

*All dimensions are nominal

TEXAS NSTRUMENTS

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TUBE

B - Alignment groove width

*All dimensions are nominal

PACKAGE OUTLINE

DGK0008A VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

DGK0008A VSSOP - 1.1 mm max height TM

SMALL OUTLINE PACKAGE

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
- on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A VSSOP - 1.1 mm max height TM

SMALL OUTLINE PACKAGE

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

12. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

D0008A SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.

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